

Phase separation in doped systems with spin-state transitions

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Spin-state transitions, observed in many transition metal compounds containing Co^{3+} and Fe^{2+} , may occur with the change of temperature, pressure, but also with doping, in which case the competition of single-site effects and kinetic energy of doped carriers can favor a change in the spin state. We consider this situation in a simple model, formally resembling that used for manganites in Ref. 1. Based on such a model, we predict the possibility of a jump-like change in the number of Co^{3+} ions undergoing spin-state transition caused by hole doping. A tendency to the electronic phase separation within a wide doping range is demonstrated. Phase diagrams with the regions of phase separation are constructed at different values of the characteristic parameters of the model.

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I. INTRODUCTION

Interplay of different degrees of freedom and different types of ordering is a very important ingredient in determining the properties of strongly correlated electron systems. Especially interesting these effects become in doped systems. Typical for this case is the tendency to phase separation and formation of inhomogeneous states. It can take different forms: formation of isolated polarons or small clusters (modification of a particular ordering by doped charge carriers and the trapping of charge carriers in a distorted region) or particular textures, e.g. stripes. Such phase separation can play a very important role in many phenomena, such as colossal magnetoresistance in manganites², and probably also in high- T_c superconductors - although their role in the latter is still a matter of hot debate.

The most common and best known case is the doping of antiferromagnetic insulators, with the formation of ferromagnetic droplets (“ferrons”) or charged antiferromagnetic domain walls (stripes)^{2,3,4}. We have recently shown that, similarly, the interplay of kinetic energy of doped holes with the orbital structure can give rise to a novel mechanism of phase separation^{5,6}.

A special interesting group of phenomena is met in systems where the respective ions can exist in different multiplet states. Typical examples are the compounds containing Co^{3+} (or sometimes Fe^{2+}), which can exist in a low-spin (LS) state with $S=0$ (t_{2g}^6), intermediate-spin (IS) state $S=1$ ($t_{2g}^5 e_g^1$), and high-spin (HS) state ($t_{2g}^4 e_g^2$) with $S=2$, see e.g. Ref. 7. Close proximity in energy of these states can lead to a special type of transition (or crossover): spin-state transition (SST), typical example being LaCoO_3 ^{7,8,9,10}. Also spin-state ordering is possible^{11,12}. Thus, these systems, in addition to quite common charge, orbital, and spin degrees of freedom with the possibility of respective orderings, have an “extra dimen-

sion”: the possibility of spin-state (or, in other words, multiplet) transitions. Correspondingly, if doping of materials like manganites can cause phase separation due to an interplay of the motion (kinetic energy) of doped holes with the underlying magnetic and orbital structure, in systems with SST like cobaltites one can expect similar phenomena due to an interplay with the spin state of the matrix. The common mechanisms causing the phase separation manifest themselves in the situation when the particular ordering existing in the system hinders the motion of doped holes. In these cases, it may be favorable to locally modify the type of ordering, facilitating the motion of the hole in such distorted region. Thus, holes can hardly move on an antiferromagnetic background, which was noticed already long ago both for the two-band (double exchange) model^{13,14} and for the single-band (Hubbard) model^{15,16}. At the same time a hole moves freely on the ferromagnetic background. As a result, ferromagnetic polarons (ferrons) may be formed close to the hole, and the gain in kinetic energy of the latter moving on the ferromagnetic background exceeds the loss of the magnetic energy^{16,17,18}.

Similarly, certain types of orbital ordering suppress hole motion, and it may be favorable to modify orbital pattern close to a hole, forming orbital polaron and facilitating motion of a hole within it^{5,19,20}. For systems with SST such a role can be played for example by the phenomenon of a spin blockade²¹: if one dopes the material with the Co^{3+} in a low-spin state ($S=0$) by electrons, the ionic state created could be Co^{2+} in a high-spin state ($S=3/2$). In this case, it is evident that it is not possible to interchange the states Co^{3+} LS and Co^{2+} HS by moving only one electron: one would end up in the “wrong” states Co^{3+} and Co^{2+} both in IS states, not in the original states (the hopping of an electron can change the spin of corresponding states only by $\pm 1/2$, whereas the spins of the original states differ by $3/2$). As a con-

sequence, an extra electron can only move in a crystal leaving the trace of wrong spin states, which will lead to a confinement and localization of this electron, similar to the case of the usual Hubbard model¹⁶.

One can “repair” this by modifying the spin state in the vicinity of a charge carrier (electron or hole), and this will finally again lead to a creation of inhomogeneous states and to phase separation. This phenomenon was actually observed in some cobaltites, e.g. in $\text{La}_{1-x}\text{Sr}_x\text{CoO}_3$. There are already many indications of phase separation and formation of inhomogeneous states in this system^{22,23,24,25,26}, but probably the most clear evidence comes from the study of very low doped LaCoO_3 . Magnetic measurements⁸ have shown that at very low doping ($< 1\%$ of Sr) the moment per doped hole (per Sr) is much bigger than that of only a LS Co^{4+} with $S = 1/2$: instead there exist magnetic impurities with unusually large spin $S = 5 - 10$, which signals that each hole is “dressed” by the magnetic cloud due to the promotion of some of neighboring Co^{3+} ions to a magnetic state. The magnetic scattering, ESR and NMR study of such system²⁷ allowed even determining the size and shape of such magnetic clusters formed around doped holes.

It is possible to use different approaches to describe theoretically the phenomenon of phase separation. First of all, it is the direct numerical investigation². Or one can assume the formation of spin-state polarons, calculate their energy and check whether and at which conditions the formation of such polarons can be energetically favorable. But the most direct way, by which one usually starts, is first to assume the existence of a homogeneous state and to check for its stability against phase separation. This was the route taken earlier by us for the double exchange model²⁸, for the situation close to a charge ordering²⁹, for two-component model of manganites^{1,30}, or for orbital ordering⁵. If the homogeneous state turns out to be unstable, then at the second step one can investigate particular types of inhomogeneous states, which can be formed. In the present paper, we follow this route for the doped systems with SST.

II. SPIN STATES OF COBALT IONS

Let us list the possible spin states of Co^{3+} and Co^{4+} ions in a CoO_6 octahedron, which is a main building block of perovskite-like Co-based compounds (we will consider below the hole-doped cobaltites, nominally containing Co^{3+} and Co^{4+}). The electron configuration of Co^{3+} ion is $3d^6$. It is well known that in the crystal field of cubic symmetry, a d -level with the 5-fold orbital degeneracy is split into a doubly degenerate e_g level and a triply degenerate t_{2g} level. In the octahedral coordination, the t_{2g} level lies below the e_g level. So, a Co^{3+} ion can have three low-energy spin states: low-spin (LS), intermediate-spin (IS), and high-spin (HS) states.

In the LS state ($S = 0$), all t_{2g} states are occupied



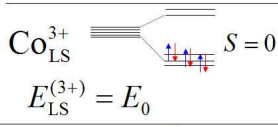
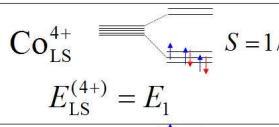
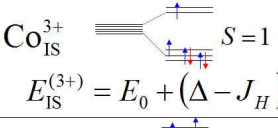
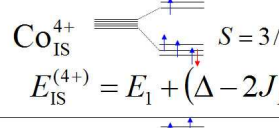
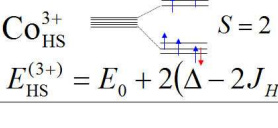
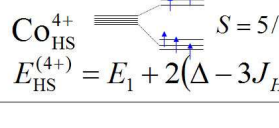
 $\text{Co}_{\text{LS}}^{3+}$ $S = 0$ $E_{\text{LS}}^{(3+)} = E_0$	 $\text{Co}_{\text{LS}}^{4+}$ $S = 1/2$ $E_{\text{LS}}^{(4+)} = E_1$
 $\text{Co}_{\text{IS}}^{3+}$ $S = 1$ $E_{\text{IS}}^{(3+)} = E_0 + (\Delta - J_H)$	 $\text{Co}_{\text{IS}}^{4+}$ $S = 3/2$ $E_{\text{IS}}^{(4+)} = E_1 + (\Delta - 2J_H)$
 $\text{Co}_{\text{HS}}^{3+}$ $S = 2$ $E_{\text{HS}}^{(3+)} = E_0 + 2(\Delta - 2J_H)$	 $\text{Co}_{\text{HS}}^{4+}$ $S = 5/2$ $E_{\text{HS}}^{(4+)} = E_1 + 2(\Delta - 3J_H)$

Table I: (Color online) Possible electron configurations of Co ions and their energies.

and the e_g level is empty. In the IS state ($S = 1$), there are five electrons at the t_{2g} level and one e_g electron. In the HS state ($S = 2$), we have four t_{2g} and two e_g electrons. The corresponding energies of these states are $E_{\text{LS}}^{(3+)} = E_0$, $E_{\text{IS}}^{(3+)} = E_0 + \Delta - J_H$, and $E_{\text{HS}}^{(3+)} = E_0 + 2\Delta - 4J_H$, where Δ is the energy splitting between t_{2g} and e_g levels and J_H is the Hund's rule coupling constant. For the Co^{4+} ion ($3d^5$), there are three similar low-lying spin states, corresponding to different distributions of five electrons between t_{2g} and e_g levels. In the LS state ($S = 1/2$), there are five electrons at the t_{2g} level and no e_g electrons. In the IS state ($S = 3/2$), we have four t_{2g} electrons and one e_g electron. In the HS state ($S = 5/2$), the numbers of t_{2g} and e_g electrons are equal to three and two, respectively. The corresponding energies of these states for the Co^{4+} ion are $E_{\text{LS}}^{(4+)} = E_1$, $E_{\text{IS}}^{(4+)} = E_1 + \Delta - 2J_H$, and $E_{\text{HS}}^{(4+)} = E_1 + 2\Delta - 6J_H$. Here, we introduced E_0 and E_1 as some reference energy values for Co^{3+} and Co^{4+} , respectively. As we shall demonstrate below, the results do not depend much on the specific choice of E_0 and E_1 . All aforementioned configurations of Co ions and their energies are summarized in Table I.

The type of the ground state for a separate Co^{3+} or Co^{4+} ion depends on the relationship between Δ and J_H . It can be easily seen that at $\Delta > 3J_H$, the LS is the ground state both for Co^{3+} and Co^{4+} . At $2J_H < \Delta < 3J_H$, Co^{3+} still has the LS ground state, whereas for Co^{4+} the HS is more favorable. Eventually, at $\Delta < 2J_H$, the HS state is the lowest in energy for both ions. Hence, for isolated cobalt ions, the IS ground state does not appear.

The situation becomes more complicated if there exists a charge transfer between cobalt ions. First, note that the hopping integrals between the t_{2g} states in cobaltites are as a rule much smaller than for the e_g states. In the treatment below, we ignore the $t_{2g} - t_{2g}$ hopping and take into account only the hopping of e_g electrons. The inclusion of $t_{2g} - t_{2g}$ hoppings will not modify qualita-

tive results, introducing only minor numerical changes. Second, the states with the number of electrons per ion larger than six are unfavorable due to the strong on-site Coulomb repulsion. Third, the transitions of electrons between the lattice sites corresponding to the changes of spin by more than one half are strongly suppressed since they involve the simultaneous change of a state for two or more electrons.

As a result, in doped cobaltites there remain only two most probable hopping processes: (i) the transitions of electrons between the IS Co^{3+} and LS Co^{4+} and (ii) transitions between the HS Co^{3+} and IS Co^{4+} . The corresponding configurations are illustrated in Table I. Thus, to facilitate the kinetic energy gain due to the electron transfer, one can create a ground state with intermediate spins. Such a situation can arise if in the ground state for isolated ions, we have either LS Co^{4+} or HS Co^{3+} . The former case corresponds to $\Delta > 3J_H$ when some of LS Co^{3+} can be promoted to the IS state. In the latter case corresponding to $\Delta < 2J_H$, some HS Co^{4+} are promoted to the IS state. In the intermediate situation, $2J_H < \Delta < 3J_H$, the electron transfer can occur if we promote both ions, Co^{3+} and Co^{4+} , to some excited states. Such double excitations seem to be less probable. Below, we first discuss the most realistic case $\Delta > 3J_H$ at different doping levels with a special emphasis on the possibility of phase separation. Then, we perform the similar study for $\Delta < 2J_H$. After that, we construct the phase diagram of the system at Δ/J_H -doping plane.

Actually, Δ , or rather Δ/t , regularly depends on the rare earth radius r_A in the series of RCoO_3 perovskites and increases with decreasing r_A .

III. CHARGE TRANSFER EFFECTS AND SPIN-STATE TRANSITIONS: THE CASE OF LS-LS GROUND STATE FOR ISOLATED IONS

Let us first discuss the situation corresponding to doped perovskite cobaltites, where Co^{3+} and Co^{4+} ions occupy the sites of a simple cubic lattice. The relative number of Co^{4+} and Co^{3+} is respectively x and $1 - x$. Let us assume that in the absence of charge transfer the cobalt ions of both types are in the LS state ($\Delta > 3J_H$); this is a typical situation e.g. in the hole-doped $\text{La}_{1-x}\text{Sr}_x\text{CoO}_3$, and even more so for smaller rare earths R in doped RCoO_3 ³¹. By promoting some Co^{3+} ions to the IS state, we can have a gain in kinetic energy related to the charge transfer from IS Co^{3+} to LS Co^{4+} .

To treat this situation in more detail, let us introduce creation operators $a_{\mathbf{n}}^\dagger$ and $c_{\mathbf{n}}^\dagger$ for an electron at the e_g level and a hole at the t_{2g} level, respectively, at site $\mathbf{n}$ according to the following rules (choosing Co_{LS}^{3+} as the vacuum state)

$$\begin{aligned} |0\rangle &= |\text{Co}_{LS}^{3+}\rangle, & E^{(vac)} &= E_0, \\ a_{\mathbf{n}}^\dagger|0\rangle &= |\text{Co}^{2+}\rangle, & E^{(2+)} &= U', \\ c_{\mathbf{n}}^\dagger|0\rangle &= |\text{Co}_{LS}^{4+}\rangle, & E^{(h)} &= E_1. \end{aligned} \quad (1)$$

In terms of these operators, the intermediate-spin state of Co^{3+} ions can be constructed in the following way

$$|\text{Co}_{IS}^{3+}\rangle = c_{\mathbf{n}}^\dagger a_{\mathbf{n}}^\dagger |0\rangle, \quad E_{IS}^{(3+)} = E_0 + \Delta - J_H = E_2. \quad (2)$$

Summing up all possible low-energy configurations, we can write the following single-site Hamiltonian

$$H_{\mathbf{n}} = E_0 + (E_1 - E_0)n_{\mathbf{n}}^h + (U' - E_0)n_{\mathbf{n}}^e + [(E_2 - E_0) - (E_1 - E_0) - (U' - E_0)]n_{\mathbf{n}}^h n_{\mathbf{n}}^e, \quad (3)$$

where $n_{\mathbf{n}}^e = a_{\mathbf{n}}^\dagger a_{\mathbf{n}}$ and $n_{\mathbf{n}}^h = c_{\mathbf{n}}^\dagger c_{\mathbf{n}}$ are the operators describing the numbers of electrons at in e_g levels and holes at t_{2g} levels, respectively. Writing (3) in a more compact form, we have

$$H_{\mathbf{n}} = [E_0 + (E_1 - E_0)(n_{\mathbf{n}}^h - n_{\mathbf{n}}^e)] + (\Delta - J_H)n_{\mathbf{n}}^e + U n_{\mathbf{n}}^e (1 - n_{\mathbf{n}}^h), \quad (4)$$

where $U = U' + E_1 - \Delta + J_H$. Taking the sum over all lattice sites and introducing the intersite hopping terms, we get

$$\begin{aligned} H &= \sum_{\mathbf{n}} [E_0 + (E_1 - E_0 - \mu)(n_{\mathbf{n}}^h - n_{\mathbf{n}}^e)] + \\ &+ \Delta_1 \sum_{\mathbf{n}} n_{\mathbf{n}}^e + U \sum_{\mathbf{n}} n_{\mathbf{n}}^e (1 - n_{\mathbf{n}}^h) \\ &- t \sum_{\langle \mathbf{n}\mathbf{m} \rangle} (a_{\mathbf{n}}^\dagger a_{\mathbf{m}} + h.c.), \end{aligned} \quad (5)$$

where $\Delta_1 = \Delta - J_H$.

In Hamiltonian (5), we took into account only the most significant hopping integral t describing the transitions of electrons from the occupied e_g level of IS Co^{3+} to the empty e_g level of LS Co^{4+} . Moreover, we assume that an electron can move only without changing the z projection of its spin, and, because of the Hund's rule coupling the spin of an itinerant (e_g) electron and the total spin of core (t_{2g}) electrons are parallel to each other. Hence, we can assume a ferromagnetic ground state and omit a spin index of electron operators. We also neglect the possible complications related to the orbital degeneracy of the e_g level occupied by a single electron; these are not crucial for the present problem.

Such simplified Hamiltonian (5) is quite similar to that of the Falicov-Kimball model³². In model (5), we have, in fact, an interplay between the electron localization in the LS state and the itinerancy in the IS state. This kind of interplay was analyzed in detail both analytically¹ and numerically³³, and a tendency for a nanoscale phase separation was demonstrated. The local (atomic scale) charge and spin inhomogeneities related to electronic phase separation were also found recently in exact calculations for small clusters³⁴. Here, following the technique suggested in Refs. 1,30, we address the specific features of the systems with the spin-state transitions.

The average numbers of e_g electrons and t_{2g} holes per site $\langle n_{\mathbf{n}}^e \rangle = n^e$ and $\langle n_{\mathbf{n}}^h \rangle = n^h$ obey the evident relationship $n^h - n^e = x$ (by electrons we mean here not the real

extra electrons, which would create the state Co^{2+} , but the electrons in the initially empty e_g levels, promoted there by the LS-IS transition, i.e. we still are dealing with the “mixture” of Co^{3+} and Co^{4+} in the hole-doped system).

Then, the energy per site can be written as

$$E^{(1)} = E_0(1 - x) + E_1x + \langle H_1 \rangle / N, - \quad (6)$$

where

$$H_1 = \Delta_1 \sum_{\mathbf{n}} n_{\mathbf{n}}^e + U \sum_{\mathbf{n}} n_{\mathbf{n}}^e (1 - n_{\mathbf{n}}^h) - t \sum_{\langle \mathbf{nm} \rangle} (a_{\mathbf{n}}^\dagger a_{\mathbf{m}} + h.c.). \quad (7)$$

Let us consider a homogeneous state corresponding to a certain density n^e of electrons promoted to the IS Co^{3+} state. We calculate the energy spectrum using the Hubbard I decoupling³⁵ in equation of motion for the one-electron Green function $G^e(\mathbf{n}, \mathbf{n}_0; t - t_0) = -i \langle T a_{\mathbf{n}}(t) a_{\mathbf{n}_0}^\dagger(t_0) \rangle$ for these promoted e_g electrons (analogous to the band (b) electrons in Refs. 1 and 33). In the frequency-momentum representation

$$G^e(\mathbf{k}, \omega) = - \frac{\omega + \mu - \Delta_1 - U n^h}{(\omega + \mu - \Delta_1 - E_1(\mathbf{k})) (\omega + \mu - \Delta_1 - E_2(\mathbf{k}))}, \quad (8)$$

where

$$E_{1,2}(\mathbf{k}) = \frac{U + \varepsilon(\mathbf{k})}{2} \mp \sqrt{\left(\frac{U - \varepsilon(\mathbf{k})}{2} \right)^2 + U \varepsilon(\mathbf{k}) (1 - n^h)}, \quad (9)$$

and $\varepsilon(\mathbf{k})$ is the energy spectrum at $U = 0$. We choose $\varepsilon(\mathbf{k})$ in the simplest tight-binding form, ignoring possible orbital effects and not taking into account the specific features of the hopping integrals of e_g electrons, [$\varepsilon(\mathbf{k}) = -2t(\cos k_x + \cos k_y + \cos k_z)$ for simple cubic lattice].

Using Eq. (8) for the Green function, we calculate the densities n^e and n^h of e_g electrons and holes. Based on these results, we can determine the dependence of the total energy on the doping level x . These calculations are similar to those performed in Ref. 1. The b electrons in Ref. 1 correspond to our e_g electrons at IS Co^{3+} ions, whereas the number of localized l electrons in Ref. 1, n_l , corresponds to the number of LS Co^{3+} ions, $1 - n^h$. Using this similarity, we could make a direct mapping between the two systems. However, in the systems with spin-state transitions there exists another homogeneous state in addition to that considered in Ref. 1. Namely, it corresponds to all Co^{3+} ions in an intermediate spin state ($n^h = 1$, $n^e = 1 - x$). Formally, in terms of a conduction band and localized level, this state can be treated as a combination of empty localized level lying below the Fermi level of the partially filled conduction band, which is in general not possible. In our case, the state corresponding to localized level disappears in the absence of LS Co^{3+} ions.

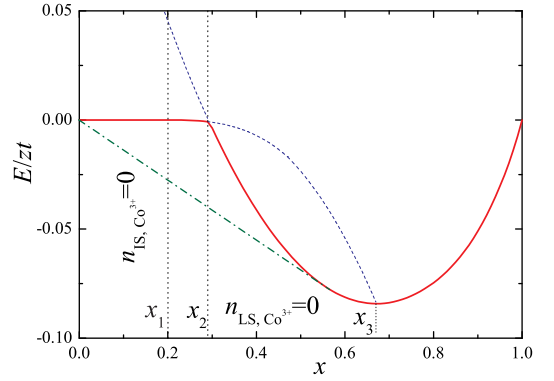


Figure 1: (Color online) The energies of type 1 and 2 states as function of doping x . The red solid curve corresponds to the more favorable in energy homogeneous state, whereas the states with higher energies are shown by blue dashed lines (see the text). The green dot-dashed line corresponds to the energy of an inhomogeneous state, obtained by Maxwell construction. $\Delta_1/zt = 0.2$.

Let us denote the state similar to that in Ref. 1 (that is the state with coexisting LS and IS Co^{3+} ions) as a type 1 state, and the state without LS Co^{3+} as type 2 state. The energies of these two states as function of doping x are shown in Fig. 1 at $\Delta_1/zt = 0.2$ ($z = 6$ is the number of nearest neighbors). The type 2 state becomes favorable at $x > x_2$. Note that at $x > x_3$ both states, 1 and 2, are equivalent. We can see that at $x < x_1$ there are no electrons promoted to the e_g level ($n^e = 0$), see Fig. 2.

At $x > x_1$ the number of e_g electrons gradually grows. In the absence of type 2 state, this growth would continue up to $x = x_3$ when all Co^{3+} ions would turn to the intermediate spin state. At $x = x_2$, however, the type 2 state becomes favorable in energy, and the jump-like transition to this state occurs. The ground state energy E for the homogeneous system as function of x is shown in Fig. 1 by red solid curve. At the same time, it is clear from this figure that in the doping range $0 < x \lesssim x_3$ the inhomogeneous state, being a mixture of states with $n^h = 1$ and $n^e = 0$, is more favorable. The energy of this mixed state is shown in Fig. 1 by the green dot-dashed line.

The densities of Co^{3+} ions in intermediate-spin (n^e) and low-spin ($1 - n^h$) states as a function of x are shown in Fig. 2 by blue dot-dashed and red solid curves, respectively. We see a jump-like increase of n^e at x_2 , when the homogeneous type 2 state would become favorable. The behavior of n^e and $1 - n^h$ at $x > x_2$ in the absence of type 2 state are shown by thin blue and red dashed lines, respectively.

At a small band filling, $n^e \ll 1$, we can write an approximate explicit expression for the total energy E as-

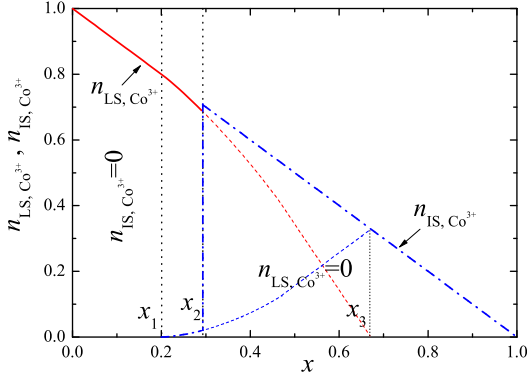


Figure 2: (Color online) The densities of Co^{3+} ions in intermediate- ($n^e = n_{\text{IS}, \text{Co}^{3+}}$) and low-spin ($1 - n^h = n_{\text{LS}, \text{Co}^{3+}}$) homogeneous states as a function of x at $\Delta_1/zt = 0.2$. At $x_1 < x < x_2$, both spin states of Co^{3+} coexist, whereas at $x = x_2$, there occurs a jump-like transition to the purely IS state of Co^{3+} ions. Dashed lines illustrate the possible behavior of $n_{\text{IS}, \text{Co}^{3+}}$ and $n_{\text{LS}, \text{Co}^{3+}}$ for the type I state similar to that described in Ref. 1.

suming that the Fermi surface is spherical

$$E \simeq \Delta_1 n^e - tz n^e n^h + \frac{3t}{5} (36\pi^4 n^h)^{1/3} (n^e)^{5/3}. \quad (10)$$

The density n^e of itinerant electrons is determined by minimization of Eq. (10) with respect to n^e taking into account that $n^h = x + n^e$. It can be easily shown that the solution for the energy minimum corresponding to $n^e \neq 0$ can exist only if $\Delta_1 < tzx$. This means that at $\Delta_1/tz > 1$ the LS Co^{3+} ions can not be promoted to the IS state at any doping x .

The dependence of n^e on doping x determines the behavior of magnetic moment of Co ions. Indeed, the LS Co^{3+} ions correspond to zero magnetic moment, $S = 0$, while the doping leads to creation of LS Co^{4+} ions ($S = 1/2$) and also provides the promotion of some Co^{3+} ions to the IS state ($S = 1$). So, the data presented in Fig. 2 could be redrawn in terms of magnetic moment per dopant (or, in other words, per Co^{4+}), see Fig. 3. For the homogeneous state, we see in Fig. 3 that the jump-like transition in the density n^e of itinerant electrons manifests itself in a jump of magnetic moment. At the same time, in the phase-separated state, the magnetic moment per Co^{4+} ion remains constant since both the content of the phase with IS Co^{3+} and the number of Co^{4+} ions are proportional to x . The value of magnetic moment per Co^{4+} is determined by the value of x , where the green dot-dashed line in Fig. 1 touches the curve corresponding to the energy of the homogeneous state. Both the height of the jump for the magnetic moment in the homogeneous state and the value of magnetic moment per Co^{4+} in the phase-separated state depend drastically in the parameters of the model, especially on the hopping integral t . In Fig. 3, we see that the increase in t by a factor of two leads to a pronounced growth of both mentioned

values. Note here that the values of magnetic moment under discussion correspond to macroscopic phase separation, that is the characteristic sizes of inhomogeneities are much larger than the lattice constant. It is indeed so at relatively large x (exceeding the percolation threshold for the phase with itinerant charge carriers). At small x , it is naturally to expect that the phase-separated system will consist of small droplets (spin-state polarons) containing only one Co^{4+} ion surrounded by IS Co^{3+} . In the latter case, the magnetic moment per Co^{4+} should be larger than that corresponding to the macroscopic phase separation. This could be the case for spin polarons in low-doped $\text{La}_{1-x}\text{Sr}_x\text{CoO}_3$ observed in Ref. 27, where the polarons with the magnetic moment equal to $13\mu_B$ seem to be the most probable. From our considerations, one should expect that the value of the moment per of Co^{4+} should become smaller with the increase of doping x . The exact calculations for small clusters also demonstrate that in a suitable range of parameters the saturated magnetic moment can exist at relatively low temperatures also in atomic-size doped clusters of various geometries³⁶.

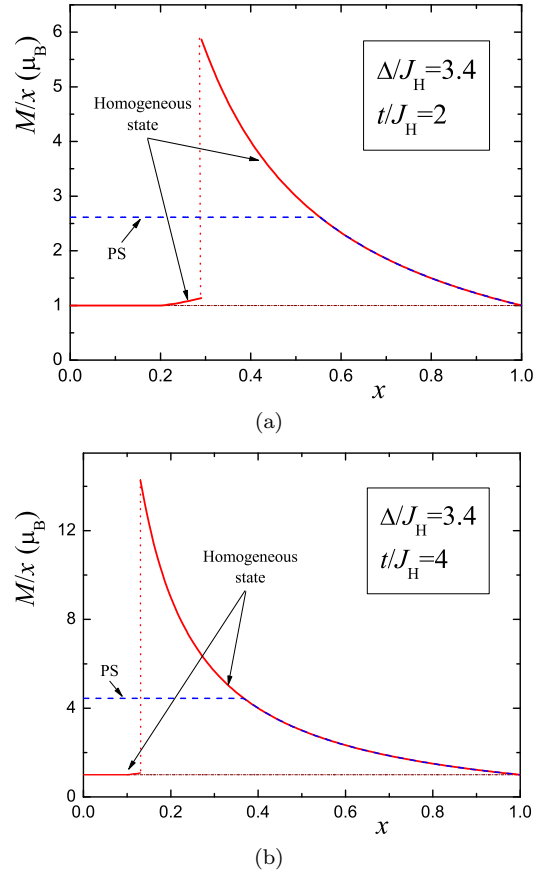


Figure 3: (Color online) Magnetic moment per one Co^{4+} ion versus doping x at different values of the hopping integral t . The red curves correspond to the homogeneous states. The behavior M in the phase-separated state is shown by the blue dashed line.

Thus, we demonstrated that the spin-state transitions in hole-doped cobaltites can be described based on the model involving the coexistence and competition of localized and itinerant electron states. In contrast to the similar model for manganites^{1,30}, this model allows the possibility of a jump-like transition to the purely itinerant state corresponding in the case of cobaltites to the LS $\rightarrow$ IS transition for all Co^{3+} ions. However, at lower doping, before reaching this homogeneous metallic state with all Co ions magnetic, the phase-separated state comes into play, in which only a part of Co^{3+} ions is promoted to the IS state, doped holes being located in these regions. Experimental data on $\text{La}_{1-x}\text{Sr}_x\text{CoO}_3$ ^{22,23,24,25,26,27} seem to be in agreement with this picture.

IV. CHARGE TRANSFER EFFECTS AND SPIN-STATE TRANSITIONS: THE CASE OF HS-HS GROUND STATE FOR ISOLATED IONS

Let us now discuss the situation at $\Delta < 2J_H$, when in the absence of electron hopping it is favorable for both Co^{3+} and Co^{4+} to be in the HS state. The charge transfer becomes possible only if we promote a hole to the e_g level of Co^{4+} and transform such an ion from HS to IS state.

So, in this case, instead of electron hopping from IS Co^{3+} to LS Co^{4+} , we have the electron hopping from the HS Co^{3+} to IS Co^{4+} , or the hole hopping from IS Co^{4+} to HS Co^{3+} (this representation is more convenient here). Using this analogy, we can choose the HS state of Co^{4+} as a new vacuum state and write relationships similar to (1) and (2) as

$$\begin{aligned} |0\rangle &= |\text{Co}_{HS}^{4+}\rangle, \quad \tilde{E}^{(vac)} = E_1 + 2\Delta - 6J_H = \tilde{E}_0, \\ \tilde{c}_{\mathbf{n}}^\dagger |0\rangle &= |\text{Co}^{5+}\rangle, \quad E^{(5+)} = \tilde{U}', \\ \tilde{a}_{\mathbf{n}}^\dagger |0\rangle &= |\text{Co}_{HS}^{3+}\rangle, \quad E^{(e)} = E_0 + 2\Delta - 4J_H = \tilde{E}_1, \\ \tilde{a}_{\mathbf{n}}^\dagger \tilde{c}_{\mathbf{n}}^\dagger |0\rangle &= |\text{Co}_{IS}^{4+}\rangle, \quad E_{IS}^{(4+)} = E_0 + \Delta - 2J_H = \tilde{E}_2. \end{aligned} \quad (11)$$

The corresponding single-site Hamiltonian can be found by the following substitution in (3) and (4): $E_0, E_1, E_2, U \rightarrow \tilde{E}_0, \tilde{E}_1, \tilde{E}_2, \tilde{U}$ and also $n_{\mathbf{n}}^e \rightarrow \tilde{n}_{\mathbf{n}}^e, n_{\mathbf{n}}^h \rightarrow \tilde{n}_{\mathbf{n}}^h$.

As a result, we can rewrite the Hamiltonian (5) in the following form

$$\begin{aligned} H &= \sum_{\mathbf{n}} [\tilde{E}_0 + (\tilde{E}_0 - \tilde{E}_1 - \mu)(\tilde{n}_{\mathbf{n}}^e - \tilde{n}_{\mathbf{n}}^h)] + \\ &+ \Delta_2 \sum_{\mathbf{n}} \tilde{n}_{\mathbf{n}}^h + \tilde{U} \sum_{\mathbf{n}} \tilde{n}_{\mathbf{n}}^h (1 - \tilde{n}_{\mathbf{n}}^h) \\ &- t \sum_{\langle \mathbf{nm} \rangle} (\tilde{c}_{\mathbf{n}}^\dagger \tilde{c}_{\mathbf{m}} + h.c.) . \end{aligned} \quad (12)$$

Here, $\Delta_2 = 4J_H - \Delta$ is the energy difference between the IS and HS Co^{4+} ions, $\tilde{c}_{\mathbf{n}}^\dagger, \tilde{c}_{\mathbf{n}}$ are creation and annihilation operators for a hole promoted to the e_g level of IS Co^{4+} at site $\mathbf{n}$, $\tilde{n}_{\mathbf{n}}^h = \tilde{c}_{\mathbf{n}}^\dagger \tilde{c}_{\mathbf{n}}$, and $\tilde{n}_{\mathbf{n}}^e = \tilde{a}_{\mathbf{n}}^\dagger \tilde{a}_{\mathbf{n}}$ is the operator describing the number (0 or 1) of additional localized

t_{2g} electrons at site $\mathbf{n}$ ($\tilde{a}_{\mathbf{n}}^\dagger, \tilde{a}_{\mathbf{n}}$ are creation and annihilation operators for such electrons). The average numbers of electrons and holes per site obey now the relationship $\tilde{n}^e - \tilde{n}^h = 1 - x$.

In this case, the energy per site (6) can be rewritten as

$$E^{(2)} = E_0(1 - x) + E_1x + \langle H_2 \rangle / N, \quad (13)$$

where

$$\begin{aligned} H_2 &= \sum_{\mathbf{n}} (2\Delta - 6J_H + 2J_H(\tilde{n}_{\mathbf{n}}^e - \tilde{n}_{\mathbf{n}}^h)) + \\ &\Delta_2 \sum_{\mathbf{n}} \tilde{n}_{\mathbf{n}}^h + \tilde{U} \sum_{\mathbf{n}} \tilde{n}_{\mathbf{n}}^h (1 - \tilde{n}_{\mathbf{n}}^h) \\ &- t \sum_{\langle \mathbf{nm} \rangle} (\tilde{a}_{\mathbf{n}}^\dagger \tilde{a}_{\mathbf{m}} + h.c.) . \end{aligned} \quad (14)$$

Note that the difference $E^{(2)} - E^{(1)}$, does not depend on the choice of E_0 and E_1 , this fact will be helpful in constructing the phase diagrams in the next section.

Thus, the behavior of the system energy and charge carrier densities, $\tilde{n}^e$ and $\tilde{n}^h$ are similar to those shown in Figs. 1 and 2. In these figures we should replace $n^h \rightarrow \tilde{n}^e$, $n^e \rightarrow \tilde{n}^h$, and $x \rightarrow 1 - x$, that is, the densities of Co^{3+} ions in IS ($n^e = n_{\text{IS}, \text{Co}^{3+}}$) and LS ($1 - n^h = n_{\text{LS}, \text{Co}^{3+}}$) states become here the densities of Co^{4+} ions in IS ($\tilde{n}^h = n_{\text{IS}, \text{Co}^{4+}}$) and HS ($1 - \tilde{n}^e = n_{\text{HS}, \text{Co}^{4+}}$) states. Note also that such an exact similarity between the LS-LS and HS-HS cases appears since we, in fact, deal with the spinless fermions (the spins of charge carriers are parallel). So, we have an electron-hole symmetry between an empty e_g level at LS Co^{3+} and a completely occupied such level at HS Co^{3+} .

V. PHASE DIAGRAMS

Based on the results of the previous sections, we can summarize the behavior of the system as function of doping at different values of the Δ/J_H ratio and to draw the corresponding phase diagram. The form of this phase diagram depends drastically on the characteristic values of the hopping integral t . The general features of the evolution of the system with doping from one homogeneous state to another are illustrated in Fig. 4. At rather small t ($t/J_H \lesssim 1$), see Fig. 4a, we have clearly defined regions of the phase diagram corresponding to $\Delta > 3J_H$ and $\Delta < 2J_H$ (corresponding to the situations discussed in sections III and IV, respectively). In each of these regions, the variation of doping leads to the transitions between the phase with only localized carriers to the phase when some charge carriers are delocalized and, eventually, to the phase when all charge carriers are itinerant. These two regions, with $\Delta > 3J_H$ and $\Delta < 2J_H$, are separated by the phase with Co^{3+} in LS ($S = 0$) and Co^{4+} in HS ($S = 5/2$) states, with the charge carriers localized because of the spin blockade²¹. At larger t ($t/J_H \gtrsim 1$),

see Fig. 4b, the latter intermediate region collapses at a certain doping range, and a direct spin-state transition between the phases with fully delocalized charge carriers becomes possible.

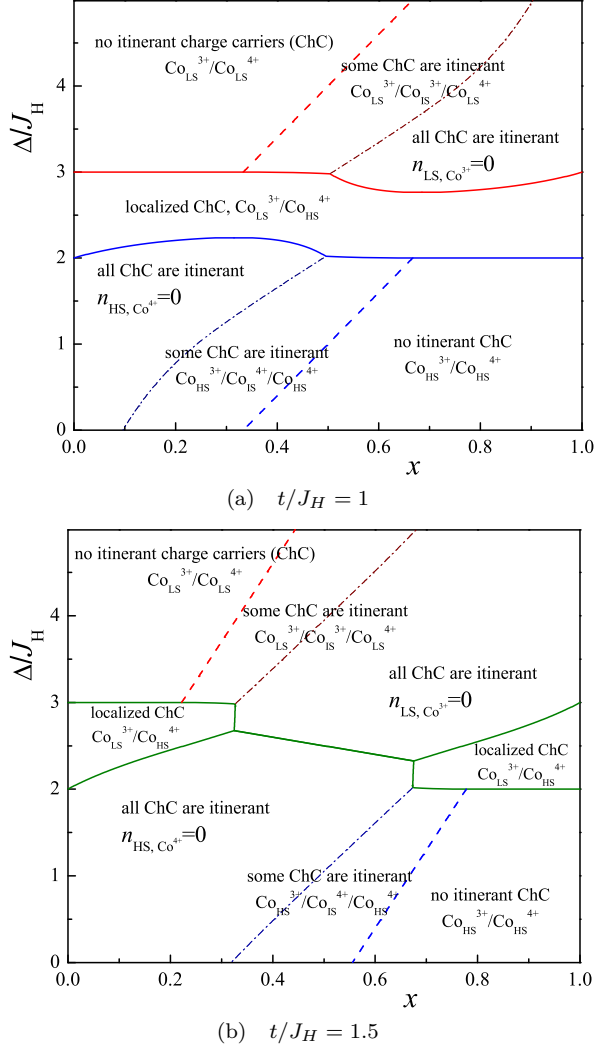


Figure 4: (Color online) Possible homogeneous states of the system under study at different values of the hopping integral t . The boundaries between analogous phases in the upper and lower parts of the phase diagram are shown by the same lines (solid, dashed, or dot-and-dash).

The form of the phase diagram changes if we take into account the possibility of phase separation. The corresponding phase diagrams drawn at different values of t/J_H are shown in Fig. 5. We see that instead of phases with partially and fully delocalized charge carriers, there appears a broad regions of phase separation where the domains of fully localized and fully delocalized charge carriers are intermixed. Again, at rather small t ($t/J_H \lesssim 1$), we have an intermediate region where the charge carriers are localized at any doping level (with Co^{3+} and Co^{4+} in LS and HS states, respectively). This intermediate region gradually disappears with the growth of the hopping

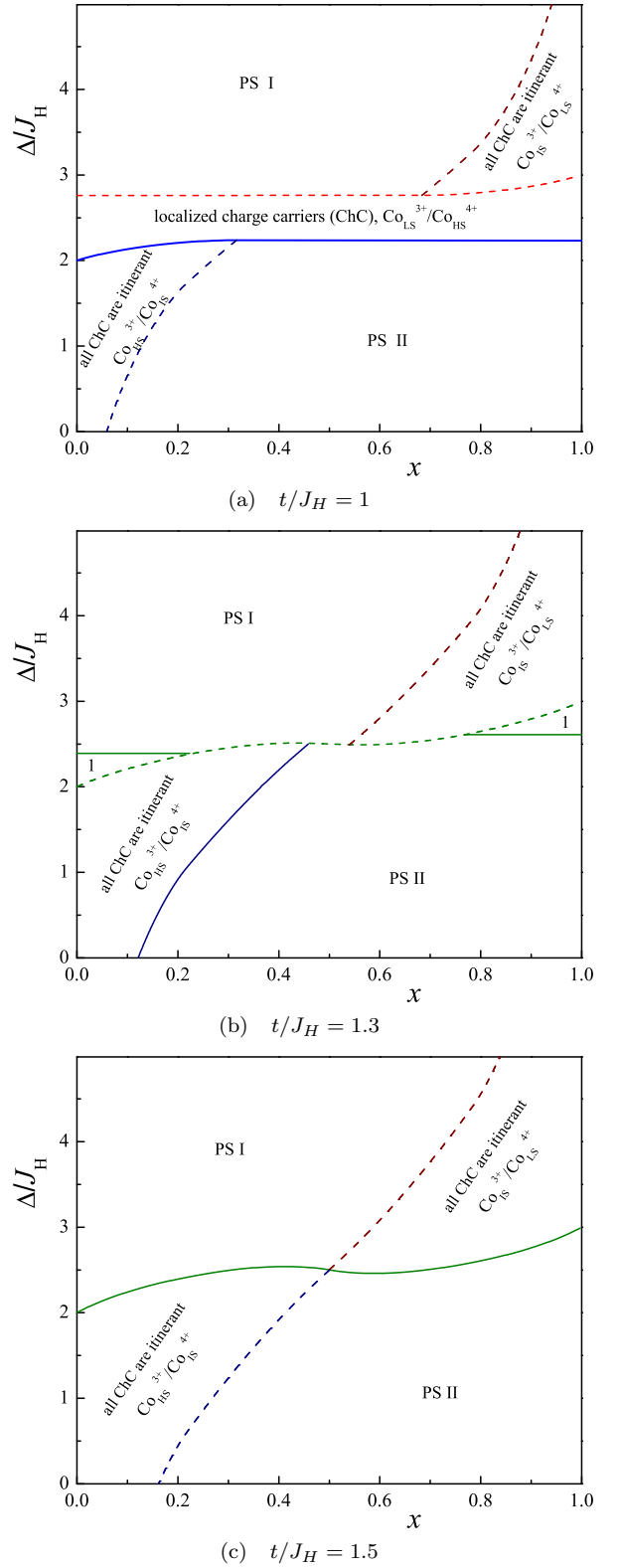


Figure 5: (Color online) Phase diagrams including the phase-separated states of the system under study at different values of hopping integral t . PS I is the phase-separated state including the regions without itinerant charge carriers, corresponding to LS Co^{3+} , and those with completely delocalized charge carriers promoted to IS Co^{3+} . PS II is the similar phase-separated state where the regions with and without itinerant charge carriers correspond to IS Co^{4+} and HS Co^{4+} , respectively. Regions 1 at panel (b) correspond to the charge carriers located at HS Co^{4+} and LS Co^{3+} where the charge transfer between Co sites is suppressed due to the spin blockade.

integral t .

Let us note here that the phase diagram along the Δ axis could be reproduced varying the average ionic radius of the rare-earth ions in cobaltites (see, e.g. Refs. 37, 38).

Note also that the long-range Coulomb interaction related to the charge disproportionation in the phase-separated state can reduce the doping range of the phase separation and modify the form of the phase diagram shown in Fig. 5.

VI. CONCLUSIONS

Based on a simplified model of a strongly correlated electron system with spin-state transitions, we demonstrated a tendency to the phase separation for doped perovskite cobaltites in a wide range of doping levels. The phase diagram including large regions of inhomogeneous phase-separated states was constructed in the plane of parameters doping x versus $e_g - t_{2g}$ energy splitting Δ . The form of the phase diagram turns out to be strongly

dependent on the ratio of the electron hopping integral t and the Hund's rule coupling constant J_H .

Here, we did not analyze in detail the possible structure of the phase-separated state. However, for the corresponding model describing doped manganites, the calculations¹ and numerical simulations³³ taking into account the surface and long-range Coulomb contributions to the total energy lead to the characteristic size of nanoscale inhomogeneities of the order of several lattice constants.

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